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Applicant: Shunpei YAMAZAKI

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U.S. PATENT DOCUMENTS

Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing Date (if appropriate)
AB	5,923,962	7/13/99	Ohtani et al.			
AB	5,643,826	7/1/97	Ohtani et al.			

FOREIGN PATENT DOCUMENTS

	Document Number	Date	Country	Class	Subclass	Translation Yes No
AB	7-130652	5/19/95	Japan			Abstract
AB	9-312260	12/2/97	Japan			Abstract
AB	64-31466	2/1/89	Japan			Abstract
AB	1-270310	10/27/89	Japan			Abstract
AB	7-263697	10/13/95	Japan			Abstract
AB	9-283439	10/31/97	Japan			Abstract
AB	10-229201	8/25/98	Japan			Abstract

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

AB	C.S. McCormick et al., "Low temperature fabrication of amorphous silicon thin film transistors by dc reactive magnetron sputtering", J. Vac. Sci. Technol. A 15(5), September/October 1997, pp. 2770-2776.

Examiner

Date Considered

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